



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT APPLICATION of : Allowed: June 2, 2005

Jin-Sung Kim et al. : Group Art Unit: 2823

Application No.: 10/697,053 : Examiner: Pham, Thanh V.

Filed: October 31, 2003

METHOD OF FORMING A POROUS MATERIAL LAYER IN A SEMICONDUCTOR

DEVICE

AMENDMENT AFTER ALLOWANCE

U.S. Patent and Trademark Office

Customer Service Window, Mail Stop Issue Fee

Randolph Building

401 Dulany Street

Alexandria VA 22314

Sir:

Subsequent to the issuance of a Notice of Allowance dated June 2, 2005, and prior to the payment of the issue fee, please amend the above-identified application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks/Arguments begin on page 5 of this paper.